# Low Voltage, Rail-to-Rail Operational Amplifiers

The MC33201/2/4 family of operational amplifiers provide rail-to-rail operation on both the input and output. The inputs can be driven as high as 200 mV beyond the supply rails without phase reversal on the outputs, and the output can swing within 50 mV of each rail. This rail-to-rail operation enables the user to make full use of the supply voltage range available. It is designed to work at very low supply voltages ( $\pm 0.9$  V) yet can operate with a supply of up to +12 V and ground. Output current boosting techniques provide a high output current capability while keeping the drain current of the amplifier to a minimum. Also, the combination of low noise and distortion with a high slew rate and drive capability make this an ideal amplifier for audio applications.

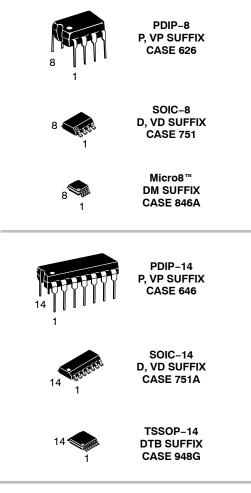
## Features

- Low Voltage, Single Supply Operation (+1.8 V and Ground to +12 V and Ground)
- Input Voltage Range Includes both Supply Rails
- Output Voltage Swings within 50 mV of both Rails
- No Phase Reversal on the Output for Over-driven Input Signals
- High Output Current (I<sub>SC</sub> = 80 mA, Typ)
- Low Supply Current (I<sub>D</sub> = 0.9 mA, Typ)
- 600  $\Omega$  Output Drive Capability
- Extended Operating Temperature Ranges (-40° to +105°C and -55° to +125°C)
- Typical Gain Bandwidth Product = 2.2 MHz
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant



# **ON Semiconductor®**

www.onsemi.com

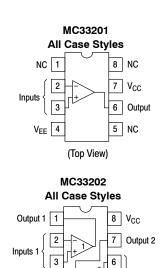


## ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

### **DEVICE MARKING INFORMATION**

See general marking information in the device marking section on page 11 of this data sheet.

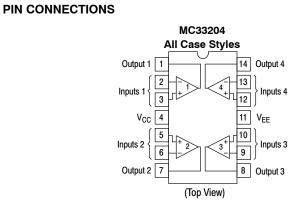


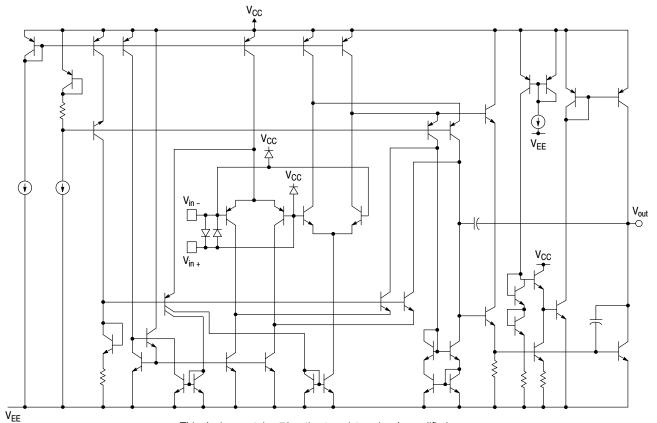
V<sub>EE</sub> 4

Inputs 2

5

(Top View)





This device contains 70 active transistors (each amplifier).

Figure 1. Circuit Schematic (Each Amplifier)

#### MAXIMUM RATINGS

| Rating   | Symbol           | Value   | Unit |
|--|------------------|---|------|
| Supply Voltage (V <sub>CC</sub> to V <sub>EE</sub> ) | VS               | +13   | V    |
| Input Differential Voltage Range                     | V <sub>IDR</sub> | Note 1  | V    |
| Common Mode Input Voltage Range (Note 2)             | V <sub>CM</sub>  | V <sub>CC</sub> + 0.5 V to<br>V <sub>EE</sub> – 0.5 V | V    |
| Output Short Circuit Duration                        | t <sub>s</sub>   | Note 3  | sec  |
| Maximum Junction Temperature                         | TJ               | +150  | °C   |
| Storage Temperature                                  | T <sub>stg</sub> | – 65 to +150  | °C   |
| Maximum Power Dissipation                            | PD               | Note 3  | mW   |

## DC ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = $25^{\circ}$ C)

| Characteristic  | V <sub>CC</sub> = 2.0 V | V <sub>CC</sub> = 3.3 V | V <sub>CC</sub> = 5.0 V | Unit                                 |
|---|-------------------------|-------------------------|-------------------------|--------------------------------------|
| Input Offset Voltage  |                         |                         |                         | mV                                   |
| V <sub>IO (max)</sub><br>MC33201, NCV33201V<br>MC33202, NCV33202, V<br>MC33204, NCV33204, V | ± 8.0<br>±10<br>±12     | ± 8.0<br>±10<br>±12     | ± 6.0<br>± 8.0<br>±10   |                                      |
| Output Voltage Swing $V_{OH}$ (R <sub>L</sub> = 10 kΩ) $V_{OL}$ (R <sub>L</sub> = 10 kΩ)    | 1.9<br>0.10             | 3.15<br>0.15            | 4.85<br>0.15            | V <sub>min</sub><br>V <sub>max</sub> |
| Power Supply Current<br>per Amplifier (I <sub>D</sub> )                                     | 1.125                   | 1.125                   | 1.125                   | mA                                   |

Specifications at V<sub>CC</sub> = 3.3 V are guaranteed by the 2.0 V and 5.0 V tests. V<sub>EE</sub> = GND.

## **DC ELECTRICAL CHARACTERISTICS** ( $V_{CC}$ = + 5.0 V, $V_{EE}$ = Ground, $T_A$ = 25°C, unless otherwise noted.)

| Characteristic  | Figure | Symbol                     | Min | Тур | Max | Unit  |
|---|--------|----------------------------|-----|-----|-----|-------|
| Input Offset Voltage (V <sub>CM</sub> 0 V to 0.5 V, V <sub>CM</sub> 1.0 V to 5.0 V) | 3      | v <sub>io</sub>            |     |     |     | mV    |
| MC33201/NCV33201V: $T_A = +25^{\circ}C$   |        |                            | -   | -   | 6.0 |       |
| MC33201: $T_A = -40^{\circ} \text{ to } +105^{\circ}\text{C}$                       |        |                            | -   | -   | 9.0 |       |
| MC33201V/NCV33201V: T <sub>A</sub> = - 55° to +125°C                                |        |                            | -   | -   | 13  |       |
| MC33202/NCV33202, V: $T_A = +25^{\circ}C$   |        |                            | -   | -   | 8.0 |       |
| MC33202/NCV33202: $T_A = -40^{\circ} \text{ to } +105^{\circ}\text{C}$              |        |                            | -   | -   | 11  |       |
| MC33202V/NCV33202V: $T_A = -55^{\circ} \text{ to } +125^{\circ}\text{C}$ (Note 4)   |        |                            | -   | -   | 14  |       |
| MC33204/NCV33204V: $T_A = + 25^{\circ}C$  |        |                            | -   | -   | 10  |       |
| MC33204: $T_A = -40^{\circ} \text{ to } +105^{\circ}\text{C}$                       |        |                            | -   | -   | 13  |       |
| MC33204V/NCV33204V: $T_A = -55^{\circ} \text{ to } +125^{\circ}\text{C}$ (Note 4)   |        |                            | -   | -   | 17  |       |
| Input Offset Voltage Temperature Coefficient ( $R_S = 50 \Omega$ )                  | 4      | $\Delta V_{IO} / \Delta T$ |     |     |     | μV/°C |
| $T_A = -40^{\circ} \text{ to } +105^{\circ}\text{C}$                                |        |                            | -   | 2.0 | -   |       |
| $T_{A} = -55^{\circ} \text{ to } +125^{\circ}\text{C}$                              |        |                            | -   | 2.0 | -   |       |
| Input Bias Current ( $V_{CM}$ = 0 V to 0.5 V, $V_{CM}$ = 1.0 V to 5.0 V)            | 5, 6   | I <sub>IB</sub>            |     |     |     | nA    |
| $T_{A} = + 25^{\circ}C$   |        |                            | -   | 80  | 200 |       |
| $T_A = -40^{\circ} \text{ to } +105^{\circ}\text{C}$                                |        |                            | -   | 100 | 250 |       |
| $T_A = -55^{\circ} \text{ to } +125^{\circ}\text{C}$                                |        |                            | -   | -   | 500 |       |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The differential input voltage of each amplifier is limited by two internal parallel back-to-back diodes. For additional differential input voltage range, use current limiting resistors in series with the input pins.

2. The input common mode voltage range is limited by internal diodes connected from the inputs to both supply rails. Therefore, the voltage on either input must not exceed either supply rail by more than 500 mV.

3. Power dissipation must be considered to ensure maximum junction temperature (T<sub>J</sub>) is not exceeded. (See Figure 2)

4. All NCV devices are qualified for Automotive use.

| Characteristic   | Figure   | Symbol   | Min                    | Тур                          | Max                    | Unit |
|--|----------|--|------------------------|------------------------------|------------------------|------|
| Input Offset Current (V <sub>CM</sub> = 0 V to 0.5 V, V <sub>CM</sub> = 1.0 V to 5.0 V)<br>$T_A = + 25^{\circ}C$<br>$T_A = - 40^{\circ}$ to +105°C<br>$T_A = - 55^{\circ}$ to +125°C | -        | I <sub>IO</sub>  | -<br>-<br>-            | 5.0<br>10<br>-               | 50<br>100<br>200       | nA   |
| Common Mode Input Voltage Range  | -        | V <sub>ICR</sub>   | V <sub>EE</sub>        | -                            | V <sub>CC</sub>        | V    |
| Large Signal Voltage Gain (V_CC = + 5.0 V, V_EE = - 5.0 V) $R_L$ = 10 $k\Omega$ $R_L$ = 600 $\Omega$   | 7        | A <sub>VOL</sub>   | 50<br>25               | 300<br>250                   |                        | kV/V |
| Output Voltage Swing (V <sub>ID</sub> = $\pm$ 0.2 V)<br>R <sub>L</sub> = 10 kΩ<br>R <sub>L</sub> = 10 kΩ<br>R <sub>L</sub> = 600 Ω<br>R <sub>L</sub> = 600 Ω                         | 8, 9, 10 | V <sub>OH</sub><br>V <sub>OL</sub><br>V <sub>OH</sub><br>V <sub>OL</sub> | 4.85<br>-<br>4.75<br>- | 4.95<br>0.05<br>4.85<br>0.15 | _<br>0.15<br>_<br>0.25 | V    |
| Common Mode Rejection (V <sub>in</sub> = 0 V to 5.0 V)   | 11       | CMR  | 60                     | 90                           | -                      | dB   |
| Power Supply Rejection Ratio<br>V <sub>CC</sub> /V <sub>EE</sub> = 5.0 V/GND to 3.0 V/GND  | 12       | PSRR   | 500                    | 25                           | -                      | μV/V |
| Output Short Circuit Current (Source and Sink)   | 13, 14   | I <sub>SC</sub>  | 50                     | 80                           | -                      | mA   |
| Power Supply Current per Amplifier (V <sub>O</sub> = 0 V)<br>$T_A = -40^{\circ}$ to +105°C<br>$T_A = -55^{\circ}$ to +125°C  | 15       | Ι <sub>D</sub>   |                        | 0.9<br>0.9                   | 1.125<br>1.125         | mA   |

#### **DC ELECTRICAL CHARACTERISTICS (cont.)** ( $V_{CC} = +5.0 \text{ V}$ , $V_{EE} = \text{Ground}$ , $T_A = 25^{\circ}\text{C}$ , unless otherwise noted.)

## $\label{eq:constraint} \textbf{AC ELECTRICAL CHARACTERISTICS} \quad (V_{CC} = + \ 5.0 \ \text{V}, \ V_{EE} = \text{Ground}, \ T_{A} = 25^{\circ}\text{C}, \ \text{unless otherwise noted.})$

| Characteristic  | Figure     | Symbol          | Min | Тур            | Max | Unit       |
|---|------------|-----------------|-----|----------------|-----|------------|
| Slew Rate (V_S = $\pm$ 2.5 V, V_O = $-$ 2.0 V to + 2.0 V, R_L = 2.0 kΩ, A_V = +1.0)   | 16, 26     | SR              | 0.5 | 1.0            | -   | V/µs       |
| Gain Bandwidth Product (f = 100 kHz)  | 17         | GBW             | -   | 2.2            | -   | MHz        |
| Gain Margin ( $R_L$ = 600 $\Omega$ , $C_L$ = 0 pF)  | 20, 21, 22 | A <sub>M</sub>  | -   | 12             | -   | dB         |
| Phase Margin ( $R_L = 600 \Omega$ , $C_L = 0 pF$ )  | 20, 21, 22 | Ø <sub>M</sub>  | -   | 65             | -   | Deg        |
| Channel Separation (f = 1.0 Hz to 20 kHz, $A_V$ = 100)  | 23         | CS              | -   | 90             | -   | dB         |
| Power Bandwidth (V_O = 4.0 V_{pp}, R_L = 600 $\Omega$ , THD $\leq$ 1 %)   |            | BWP             | -   | 28             | -   | kHz        |
| Total Harmonic Distortion (R <sub>L</sub> = 600 $\Omega,$ V <sub>O</sub> = 1.0 V <sub>pp</sub> , A <sub>V</sub> = 1.0) f = 1.0 kHz f = 10 kHz | 24         | THD             |     | 0.002<br>0.008 |     | %          |
| Open Loop Output Impedance $(V_O = 0 V, f = 2.0 MHz, A_V = 10)$   |            | z <sub>o</sub>  | _   | 100            | _   | Ω          |
| Differential Input Resistance (V <sub>CM</sub> = 0 V)   |            | R <sub>in</sub> | -   | 200            | -   | kΩ         |
| Differential Input Capacitance (V <sub>CM</sub> = 0 V)  |            | C <sub>in</sub> | -   | 8.0            | -   | pF         |
| Equivalent Input Noise Voltage ( $R_S = 100 \Omega$ )<br>f = 10 Hz<br>f = 1.0 kHz   | 25         | e <sub>n</sub>  |     | 25<br>20       |     | nV/<br>√Hz |
| Equivalent Input Noise Current<br>f = 10 Hz<br>f = 1.0 kHz  | 25         | i <sub>n</sub>  |     | 0.8<br>0.2     |     | pA/<br>√Hz |

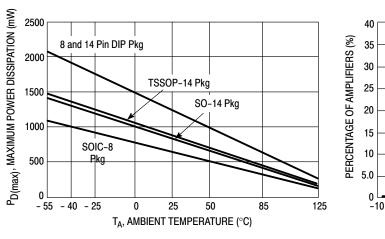


Figure 2. Maximum Power Dissipation versus Temperature

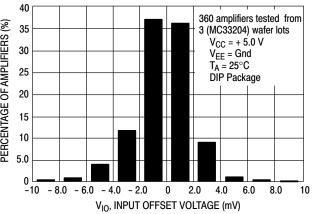


Figure 3. Input Offset Voltage Distribution

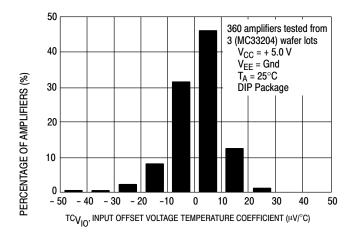


Figure 4. Input Offset Voltage Temperature Coefficient Distribution

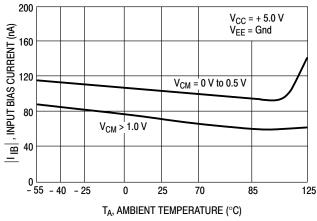
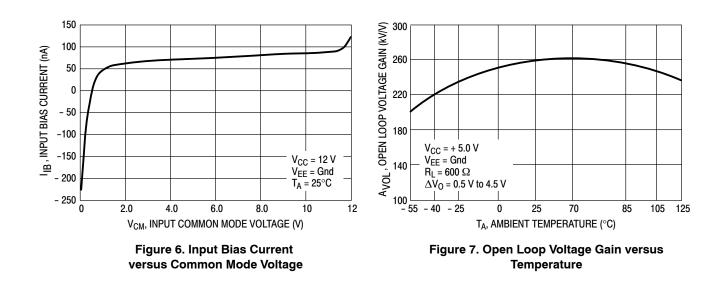
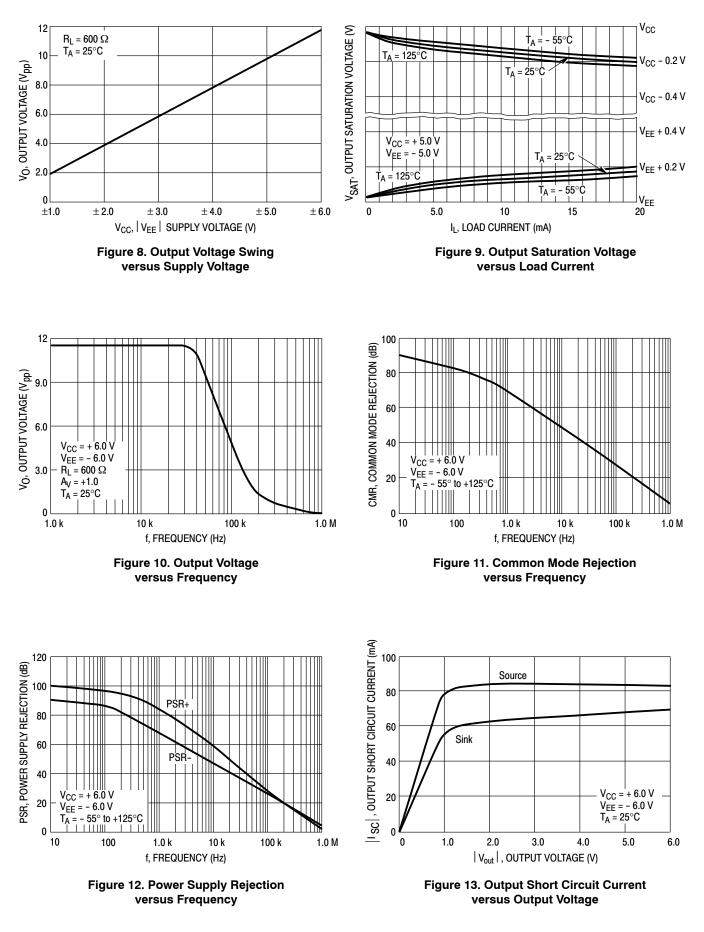
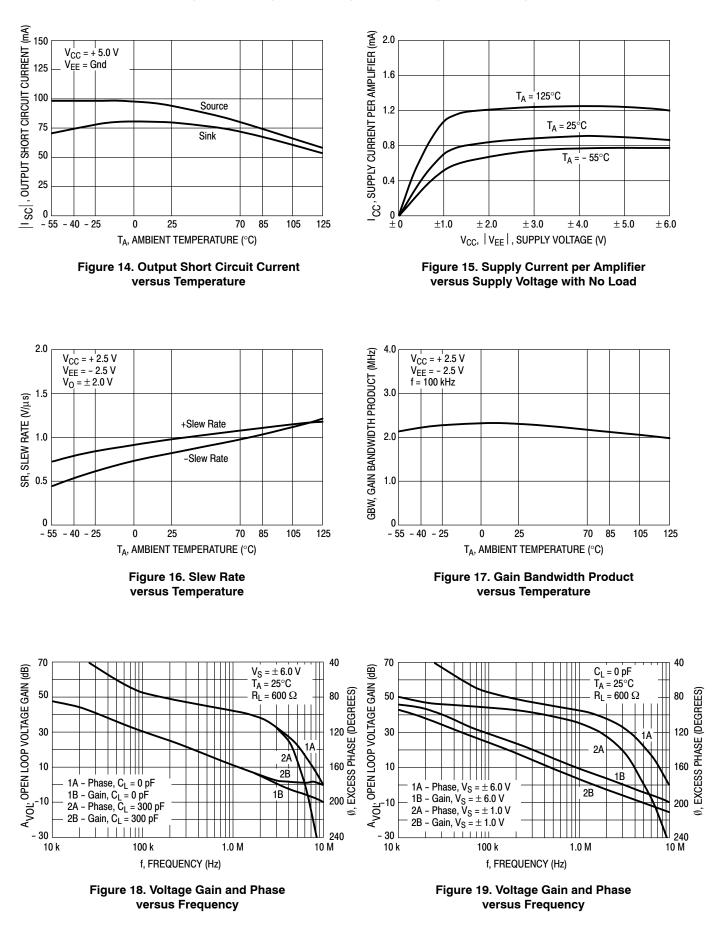
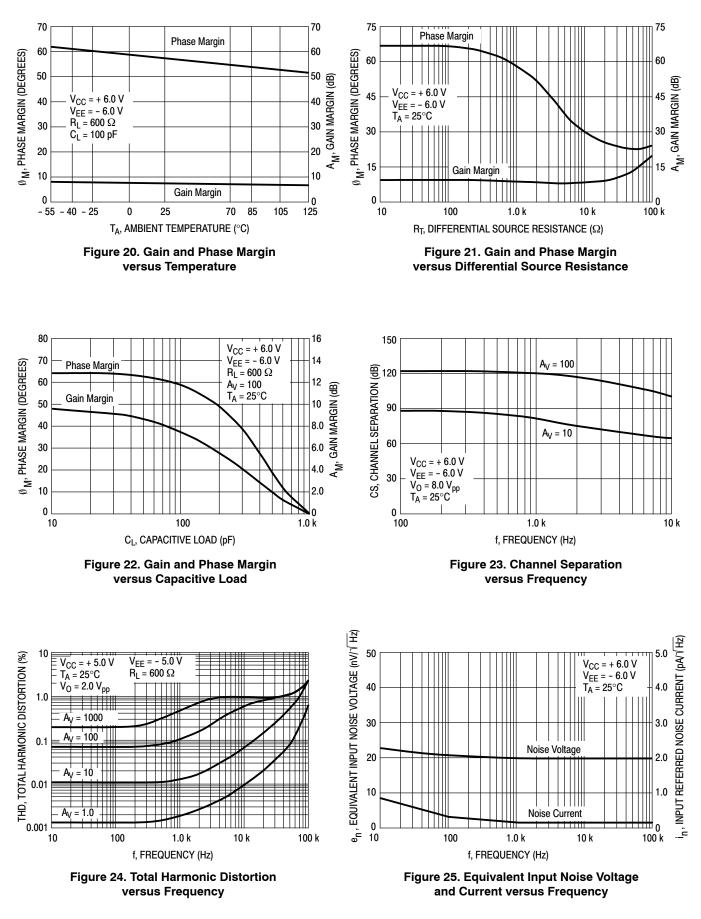


Figure 5. Input Bias Current versus Temperature









## DETAILED OPERATING DESCRIPTION

#### **General Information**

The MC33201/2/4 family of operational amplifiers are unique in their ability to swing rail-to-rail on both the input and the output with a completely bipolar design. This offers low noise, high output current capability and a wide common mode input voltage range even with low supply voltages. Operation is guaranteed over an extended temperature range and at supply voltages of 2.0 V, 3.3 V and 5.0 V and ground.

Since the common mode input voltage range extends from  $V_{CC}$  to  $V_{EE}$ , it can be operated with either single or split voltage supplies. The MC33201/2/4 are guaranteed not to latch or phase reverse over the entire common mode range, however, the inputs should not be allowed to exceed maximum ratings.

### **Circuit Information**

Rail-to-rail performance is achieved at the input of the amplifiers by using parallel NPN-PNP differential input stages. When the inputs are within 800 mV of the negative rail, the PNP stage is on. When the inputs are more than 800 mV greater than  $V_{EE}$ , the NPN stage is on. This switching of input pairs will cause a reversal of input bias currents (see Figure 6). Also, slight differences in offset voltage may be noted between the NPN and PNP pairs. Cross-coupling techniques have been used to keep this change to a minimum.

In addition to its rail-to-rail performance, the output stage is current boosted to provide 80 mA of output current, enabling the op amp to drive 600  $\Omega$  loads. Because of this high output current capability, care should be taken not to exceed the 150°C maximum junction temperature.

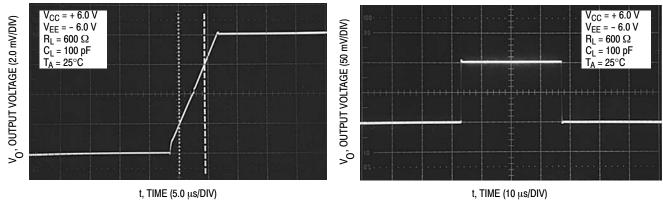


Figure 26. Noninverting Amplifier Slew Rate

Figure 27. Small Signal Transient Response

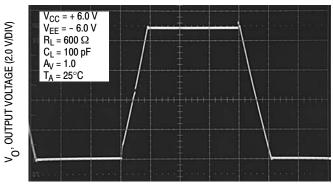




Figure 28. Large Signal Transient Response

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to ensure proper solder connection interface

between the board and the package. With the correct pad geometry, the packages will self-align when subjected to a solder reflow process.

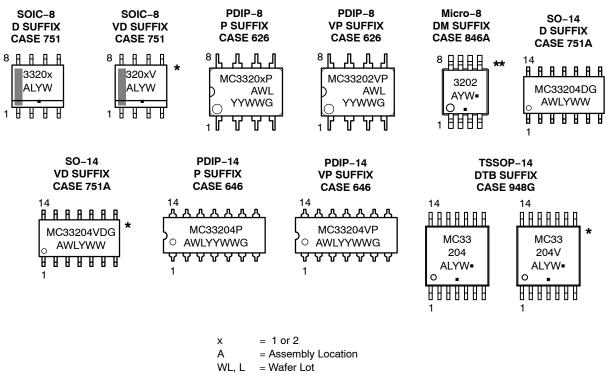
## ORDERING INFORMATION

| Operational<br>Amplifier Function | Device          | Operating<br>Temperature Range                    | Package               | Shipping <sup>†</sup>     |
|-----------------------------------|-----------------|---|-----------------------|---------------------------|
|                                   | MC33201DG       | T 1001 10500                                      | SOIC-8                | 98 Units / Rail           |
|                                   | MC33201DR2G     | $T_A = -40^\circ \text{ to } +105^\circ \text{C}$ | (Pb-Free)             | 2500 / Tape & Reel        |
| Single                            | MC33201VDG      |   |                       | 98 Units / Rail           |
|                                   | MC33201VDR2G    | $T_A = -55^\circ$ to 125°C                        |                       | 2500 / Tape & Reel        |
|                                   | NCV33201VDR2G   |   |                       | 2500 / Tape & Reel        |
|                                   | MC33202DG       |   | SOIC-8                | 98 Units / Rail           |
|                                   | MC33202DR2G     | T 40.0 to 10500                                   | (Pb-Free)             | 2500 / Tape & Reel        |
|                                   | MC33202DMR2G    | T <sub>A</sub> = -40 ° to +105°C                  | Micro-8               | 1000 / Tana & Daal        |
| Dual                              | NCV33202DMR2G*  |   | (Pb-Free)             | 4000 / Tape & Reel        |
|                                   | MC33202VDG      | T <sub>A</sub> = -55° to 125°C                    | SOIC-8<br>(Pb-Free)   | 98 Units / Rail           |
|                                   | MC33202VDR2G    |   |                       |                           |
|                                   | NCV33202VDR2G*  | V33202VDR2G*                                      |                       | 2500 / Tape & Reel        |
|                                   | MC33204DG       |   | SO-14                 | 55 Units / Rail           |
|                                   | MC33204DR2G     | T 40.045 x 10500                                  | (Pb-Free)             | 2500 Units / Tape & Reel  |
|                                   | MC33204DTBG     | T <sub>A</sub> = -40 ° to +105°C                  | TSSOP-14              | 96 Units / Rail           |
|                                   | MC33204DTBR2G   |   | (Pb-Free)             | 2500 Units / Tape & Reel  |
| Quad                              | MC33204VDG      |   | SO-14                 | 55 Units / Rail           |
|                                   | MC33204VDR2G    |   | (Pb-Free)             | 0500 Linita / Tana & Daal |
|                                   | NCV33204DR2G*   | $T_A = -55^\circ$ to $125^\circ$ C                |                       | 2500 Units / Tape & Reel  |
|                                   | NCV33204DTBR2G* | ] [   | TSSOP-14<br>(Pb-Free) | 2500 Units / Tape & Reel  |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

#### MARKING DIAGRAMS



WW, W = Work Week

G = Pb-Free Package

= Pb-Free Package

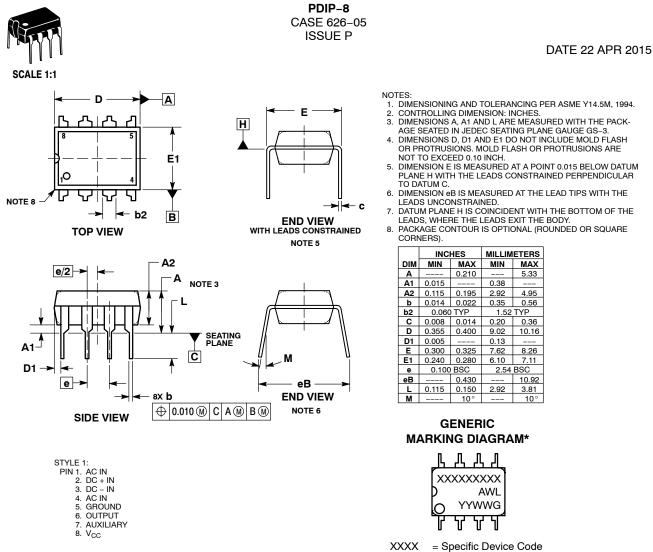
(Note: Microdot may be in either location)

\*This marking diagram applies to NCV3320xV

\*\*This marking diagram applies to NCV33202DMR2G

Micro8 is a trademark of International Rectifier.



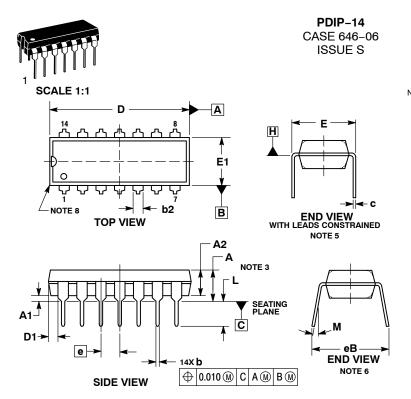


A = Assembly Location

- WL = Wafer Lot
- YY = Year
- WW = Work Week
- G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb–Free indicator, "G" or microdot " ■", may or may not be present.





**STYLES ON PAGE 2** 

#### **ON Semiconductor**

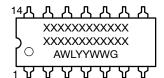


#### DATE 22 APR 2015

- NOTES:
  DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  CONTROLLING DIMENSION: INCHES.
  DIMENSIONS A, A1 AND L ARE MEASURED WITH THE PACK-AGE SEATED IN JEDEC SEATING PLANE GAUGE GS-3.
  DIMENSIONS D, D1 AND E1 DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS ARE NOT DE VICE DA 10 INCH. NOT TO EXCEED 0.10 INCH. DIMENSION E IS MEASURED AT A POINT 0.015 BELOW DATUM
- 5. PLANE H WITH THE LEADS CONSTRAINED PERPENDICULAR TO DATUM C.
- 6.
- DIMENSION & BIS MEASURED AT THE LEAD TIPS WITH THE LEADS UNCONSTRAINED. DATUM PLANE H IS COINCIDENT WITH THE BOTTOM OF THE LEADS, WHERE THE LEADS EXIT THE BODY. PACKAGE CONTOUR IS OPTIONAL (ROUNDED OR SQUARE CODNEPS) 7.
- 8. CORNERS).

|     | · ·    |           |          |       |
|-----|--------|-----------|----------|-------|
|     | INCHES |           | MILLIM   | ETERS |
| DIM | MIN    | MAX       | MIN      | MAX   |
| Α   |        | 0.210     |          | 5.33  |
| A1  | 0.015  |           | 0.38     |       |
| A2  | 0.115  | 0.195     | 2.92     | 4.95  |
| b   | 0.014  | 0.022     | 0.35     | 0.56  |
| b2  | 0.060  | 0.060 TYP |          | TYP   |
| С   | 0.008  | 0.014     | 0.20     | 0.36  |
| D   | 0.735  | 0.775     | 18.67    | 19.69 |
| D1  | 0.005  |           | 0.13     |       |
| Е   | 0.300  | 0.325     | 7.62     | 8.26  |
| E1  | 0.240  | 0.280     | 6.10     | 7.11  |
| е   | 0.100  | BSC       | 2.54 BSC |       |
| eB  |        | 0.430     |          | 10.92 |
| L   | 0.115  | 0.150     | 2.92     | 3.81  |
| М   |        | 10°       |          | 10°   |

#### GENERIC **MARKING DIAGRAM\***



XXXXX = Specific Device Code

- = Assembly Location
- WL = Wafer Lot
- YY = Year

А

G

- ww = Work Week
  - = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " .", may or may not be present.

| DOCUMENT NUMBER:  | 98ASB42428B   | Electronic versions are uncontrolled except when accessed directly from the Document Repo<br>Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |   |  |  |  |  |  |  |
|---|---|--|---|--|--|--|--|--|--|
| DESCRIPTION:  | ON: PDIP-14   |  | PAGE 1 OF 2   |  |  |  |  |  |  |
| ON Semiconductor reserves the right<br>the suitability of its products for any pa | to make changes without further notice to an<br>articular purpose, nor does ON Semiconducto | y products herein. ON Semiconductor makes no warranty, representation<br>r assume any liability arising out of the application or use of any product or                      | ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries.<br>ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding<br>the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically<br>disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the |  |  |  |  |  |  |

© Semiconductor Components Industries, LLC, 2019

#### PDIP-14 CASE 646-06 ISSUE S

## DATE 22 APR 2015

| STYLE 1:<br>PIN 1. COLLECTOR<br>2. BASE<br>3. EMITTER<br>4. NO<br>CONNECTION<br>5. EMITTER<br>6. BASE<br>7. COLLECTOR<br>8. COLLECTOR<br>9. BASE<br>10. EMITTER<br>11. NO<br>CONNECTION<br>12. EMITTER<br>13. BASE<br>14. COLLECTOR   | STYLE 2:<br>CANCELLED  | STYLE 3:<br>CANCELLED   | STYLE 4:<br>PIN 1. DRAIN<br>2. SOURCE<br>3. GATE<br>4. NO<br>CONNECTION<br>5. GATE<br>6. SOURCE<br>7. DRAIN<br>8. DRAIN<br>9. SOURCE<br>10. GATE<br>11. NO<br>CONNECTION<br>12. GATE<br>13. SOURCE<br>14. DRAIN   |
|---|--|---|---|
| STYLE 5:<br>PIN 1. GATE<br>2. DRAIN<br>3. SOURCE<br>4. NO CONNECTION<br>5. SOURCE<br>6. DRAIN<br>7. GATE<br>8. GATE<br>9. DRAIN<br>10. SOURCE<br>11. NO CONNECTION<br>12. SOURCE<br>13. DRAIN<br>14. GATE   | STYLE 6:<br>PIN 1. COMMON CATHODE<br>2. ANODE/CATHODE<br>3. ANODE/CATHODE<br>4. NO CONNECTION<br>5. ANODE/CATHODE<br>6. NO CONNECTION<br>7. ANODE/CATHODE<br>8. ANODE/CATHODE<br>9. ANODE/CATHODE<br>10. NO CONNECTION<br>11. ANODE/CATHODE<br>12. ANODE/CATHODE<br>13. NO CONNECTION<br>14. COMMON ANODE        | STYLE 7:<br>PIN 1. NO CONNECTION<br>2. ANODE<br>3. ANODE<br>4. NO CONNECTION<br>5. ANODE<br>6. NO CONNECTION<br>7. ANODE<br>8. ANODE<br>9. ANODE<br>10. NO CONNECTION<br>11. ANODE<br>12. ANODE<br>13. NO CONNECTION<br>14. COMMON<br>CATHODE | STYLE 8:<br>PIN 1. NO CONNECTION<br>2. CATHODE<br>3. CATHODE<br>4. NO CONNECTION<br>5. CATHODE<br>6. NO CONNECTION<br>7. CATHODE<br>8. CATHODE<br>10. NO CONNECTION<br>11. CATHODE<br>12. CATHODE<br>13. NO CONNECTION<br>14. COMMON ANODE  |
| STYLE 9:<br>PIN 1. COMMON CATHODE<br>2. ANODE/CATHODE<br>3. ANODE/CATHODE<br>4. NO CONNECTION<br>5. ANODE/CATHODE<br>6. ANODE/CATHODE<br>7. COMMON ANODE<br>8. COMMON ANODE<br>9. ANODE/CATHODE<br>10. ANODE/CATHODE<br>11. NO CONNECTION<br>12. ANODE/CATHODE<br>13. ANODE/CATHODE<br>14. COMMON CATHODE | STVLE 10:<br>PIN 1. COMMON<br>CATHODE<br>2. ANODE/CATHODE<br>3. ANODE/CATHODE<br>4. ANODE/CATHODE<br>5. ANODE/CATHODE<br>6. NO CONNECTION<br>7. COMMON ANODE<br>8. COMMON<br>CATHODE<br>9. ANODE/CATHODE<br>10. ANODE/CATHODE<br>11. ANODE/CATHODE<br>12. ANODE/CATHODE<br>13. NO CONNECTION<br>14. COMMON ANODE | STYLE 11:<br>PIN 1. CATHODE<br>2. CATHODE<br>3. CATHODE<br>4. CATHODE<br>5. CATHODE<br>6. CATHODE<br>7. CATHODE<br>8. ANODE<br>9. ANODE<br>10. ANODE<br>11. ANODE<br>12. ANODE<br>13. ANODE<br>14. ANODE                                      | STYLE 12:<br>PIN 1. COMMON CATHODE<br>2. COMMON ANODE<br>3. ANODE/CATHODE<br>4. ANODE/CATHODE<br>5. ANODE/CATHODE<br>6. COMMON ANODE<br>7. COMMON CATHODE<br>8. ANODE/CATHODE<br>10. ANODE/CATHODE<br>11. ANODE/CATHODE<br>12. ANODE/CATHODE<br>13. ANODE/CATHODE<br>14. ANODE/CATHODE<br>14. ANODE/CATHODE |

| DOCUMENT NUMBER:  | 98ASB42428B   | <b>8ASB42428B</b> Electronic versions are uncontrolled except when accessed directly from the Document Re<br>Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.   |   |  |
|---|---|--|---|--|
| DESCRIPTION:  | PDIP-14   |  | PAGE 2 OF 2   |  |
| ON Semiconductor reserves the right<br>the suitability of its products for any pa | to make changes without further notice to any<br>articular purpose, nor does ON Semiconductor | stries, LLC dba ON Semiconductor or its subsidiaries in the United States<br>y products herein. ON Semiconductor makes no warranty, representation<br>r assume any liability arising out of the application or use of any product of<br>cidental damages. ON Semiconductor does not convey any license under | or guarantee regarding<br>r circuit, and specifically |  |





\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## STYLES ON PAGE 2

| DOCUMENT NUMBER:  | 98ASB42564B   | Electronic versions are uncontrolled except when accessed directly from the Document Reposite<br>Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.  |   |  |
|---|---|---|---|--|
| DESCRIPTION:  | DN: SOIC-8 NB   |   | PAGE 1 OF 2   |  |
| ON Semiconductor reserves the right<br>the suitability of its products for any pa | to make changes without further notice to an<br>articular purpose, nor does ON Semiconducto | stries, LLC dba ON Semiconductor or its subsidiaries in the United States<br>y products herein. ON Semiconductor makes no warranty, representation<br>r assume any liability arising out of the application or use of any product on<br>ncidental damages. ON Semiconductor does not convey any license under | or guarantee regarding<br>r circuit, and specifically |  |

#### SOIC-8 NB CASE 751-07 ISSUE AK

STYLE 1: PIN 1. EMITTER COLLECTOR 2. COLLECTOR 3. 4. EMITTER EMITTER 5. BASE 6. 7 BASE EMITTER 8. STYLE 5: PIN 1. DRAIN 2. DRAIN 3. DRAIN DRAIN 4. GATE 5. 6. GATE SOURCE 7. 8. SOURCE STYLE 9: PIN 1. EMITTER, COMMON COLLECTOR, DIE #1 COLLECTOR, DIE #2 2. З. EMITTER, COMMON 4. 5. EMITTER, COMMON 6 BASE. DIE #2 BASE, DIE #1 7. 8. EMITTER, COMMON STYLE 13: PIN 1. N.C. 2. SOURCE 3 GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. DRAIN 8. STYLE 17: PIN 1. VCC 2. V2OUT V10UT З. TXE 4. 5. RXE 6. VFF 7. GND 8. ACC STYLE 21: CATHODE 1 PIN 1. 2. CATHODE 2 3 CATHODE 3 CATHODE 4 4. 5. CATHODE 5 6. COMMON ANODE COMMON ANODE 7. 8. CATHODE 6 STYLE 25: PIN 1. VIN 2 N/C REXT З. 4. GND 5. IOUT 6. IOUT IOUT 7. 8. IOUT STYLE 29: BASE, DIE #1 PIN 1. 2 EMITTER, #1 BASE, #2 З. EMITTER, #2 4. 5 COLLECTOR, #2 COLLECTOR, #2 6.

STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 COLLECTOR, #2 3. 4 COLLECTOR, #2 BASE, #2 5. EMITTER, #2 6. 7 BASE #1 EMITTER, #1 8. STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN SOURCE 4. SOURCE 5. 6. GATE GATE 7. 8. SOURCE STYLE 10: PIN 1. GROUND BIAS 1 OUTPUT 2. З. GROUND 4. 5. GROUND 6 BIAS 2 INPUT 7. 8. GROUND STYLE 14: PIN 1. N-SOURCE 2. N-GATE P-SOURCE 3 P-GATE 4. P-DRAIN 5 6. P-DRAIN N-DRAIN 7. N-DRAIN 8. STYLE 18: PIN 1. ANODE 2. ANODE SOURCE 3. GATE 4. 5. DRAIN 6 DRAIN CATHODE 7. CATHODE 8. STYLE 22 PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC COMMON CATHODE/VCC 3 4. I/O LINE 3 5. COMMON ANODE/GND 6. I/O LINE 4 7. I/O LINE 5 COMMON ANODE/GND 8. STYLE 26: PIN 1. GND 2 dv/dt З. ENABLE 4. ILIMIT 5. SOURCE SOURCE 6. SOURCE 7. 8. VCC STYLE 30: DRAIN 1 PIN 1. DRAIN 1 2 GATE 2 З. SOURCE 2 4. SOURCE 1/DRAIN 2 SOURCE 1/DRAIN 2 5. 6.

STYLE 3: PIN 1. DRAIN, DIE #1 DRAIN, #1 2. DRAIN, #2 З. 4. DRAIN, #2 GATE, #2 5. SOURCE, #2 6. 7 GATE #1 8. SOURCE, #1 STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS THIRD STAGE SOURCE GROUND З. 4. 5. DRAIN 6. GATE 3 SECOND STAGE Vd 7. FIRST STAGE Vd 8. STYLE 11: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. DRAIN 2 DRAIN 1 7. 8. DRAIN 1 STYLE 15: PIN 1. ANODE 1 2. ANODE 1 ANODE 1 3 ANODE 1 4. 5. CATHODE, COMMON CATHODE, COMMON CATHODE, COMMON 6. 7. CATHODE, COMMON 8. STYLE 19: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. MIRROR 2 DRAIN 1 7. 8. **MIRROR 1** STYLE 23: PIN 1. LINE 1 IN COMMON ANODE/GND COMMON ANODE/GND 2. 3 LINE 2 IN 4. LINE 2 OUT 5. COMMON ANODE/GND COMMON ANODE/GND 6. 7. LINE 1 OUT 8. STYLE 27: PIN 1. ILIMIT 2 OVI 0 UVLO З. 4. INPUT+ 5. SOURCE SOURCE 6. SOURCE 7. 8 DRAIN

#### DATE 16 FEB 2011

STYLE 4: ANODE ANODE PIN 1. 2. ANODE З. 4. ANODE ANODE 5. 6. ANODE 7 ANODE COMMON CATHODE 8. STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 BASE #2 3. COLLECTOR, #2 4. COLLECTOR, #2 5. 6. EMITTER, #2 EMITTER, #1 7. 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE SOURCE 2. 3. 4. GATE 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 16: PIN 1. EMITTER, DIE #1 2. BASE, DIE #1 EMITTER, DIE #2 3 BASE, DIE #2 4. 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 COLLECTOR, DIE #1 7. COLLECTOR, DIE #1 8. STYLE 20: PIN 1. SOURCE (N) GATE (N) SOURCE (P) 2. 3. 4. GATE (P) 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 24: PIN 1. BASE 2. EMITTER 3 COLLECTOR/ANODE COLLECTOR/ANODE 4. 5. CATHODE 6. CATHODE COLLECTOR/ANODE 7. 8. COLLECTOR/ANODE STYLE 28: PIN 1. SW\_TO\_GND 2. DASIC OFF DASIC\_SW\_DET З. 4. GND 5. 6. V MON VBULK 7. VBULK 8 VIN

| DOCUMENT NUMBER:   | 98ASB42564B            | Electronic versions are uncontrolled except when accessed directly from<br>Printed versions are uncontrolled except when stamped "CONTROLLED 0 |             |  |  |
|--|------------------------|--|-------------|--|--|
| DESCRIPTION:   | DESCRIPTION: SOIC-8 NB |  | PAGE 2 OF 2 |  |  |
| ON Semiconductor and we are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries.<br>ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding<br>the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically<br>disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the |                        |  |             |  |  |

SOURCE 1/DRAIN 2

7.

8. GATE 1

7.

8

rights of others

COLLECTOR, #1

COLLECTOR, #1





\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## **STYLES ON PAGE 2**

| DOCUMENT NUMBER:  | 98ASB42565B | Electronic versions are uncontrolled except when accessed directly from the Document Repository.<br>Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |             |
|---|-------------|---|-------------|
| DESCRIPTION:  | SOIC-14 NB  |   | PAGE 1 OF 2 |
| ON Semiconductor and () are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries.<br>ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding<br>the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically<br>disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights or the |             |   |             |

#### SOIC-14 CASE 751A-03 ISSUE L

### DATE 03 FEB 2016

| STYLE 1:<br>PIN 1. COMMON CATHODE<br>2. ANODE/CATHODE<br>3. ANODE/CATHODE<br>4. NO CONNECTION<br>5. ANODE/CATHODE<br>6. NO CONNECTION<br>7. ANODE/CATHODE<br>8. ANODE/CATHODE<br>9. ANODE/CATHODE<br>10. NO CONNECTION<br>11. ANODE/CATHODE<br>12. ANODE/CATHODE<br>13. NO CONNECTION<br>14. COMMON ANODE | STYLE 2:<br>CANCELLED   | STYLE 3:<br>PIN 1. NO CONNECTION<br>2. ANODE<br>3. ANODE<br>4. NO CONNECTION<br>5. ANODE<br>6. NO CONNECTION<br>7. ANODE<br>8. ANODE<br>9. ANODE<br>10. NO CONNECTION<br>11. ANODE<br>12. ANODE<br>13. NO CONNECTION<br>14. COMMON CATHODE  | STYLE 4:<br>PIN 1. NO CONNECTION<br>2. CATHODE<br>3. CATHODE<br>4. NO CONNECTION<br>5. CATHODE<br>6. NO CONNECTION<br>7. CATHODE<br>8. CATHODE<br>10. NO CONNECTION<br>11. CATHODE<br>12. CATHODE<br>13. NO CONNECTION<br>14. COMMON ANODE   |
|---|---|---|--|
| STYLE 5:<br>PIN 1. COMMON CATHODE<br>2. ANODE/CATHODE<br>3. ANODE/CATHODE<br>4. ANODE/CATHODE<br>5. ANODE/CATHODE<br>6. NO CONNECTION<br>7. COMMON ANODE<br>8. COMMON CATHODE<br>10. ANODE/CATHODE<br>11. ANODE/CATHODE<br>12. ANODE/CATHODE<br>13. NO CONNECTION<br>14. COMMON ANODE                     | STYLE 6:<br>PIN 1. CATHODE<br>2. CATHODE<br>3. CATHODE<br>4. CATHODE<br>5. CATHODE<br>6. CATHODE<br>7. CATHODE<br>8. ANODE<br>9. ANODE<br>10. ANODE<br>11. ANODE<br>12. ANODE<br>13. ANODE<br>14. ANODE | STYLE 7:<br>PIN 1. ANODE/CATHODE<br>2. COMMON ANODE<br>3. COMMON CATHODE<br>4. ANODE/CATHODE<br>5. ANODE/CATHODE<br>6. ANODE/CATHODE<br>8. ANODE/CATHODE<br>9. ANODE/CATHODE<br>10. ANODE/CATHODE<br>11. COMMON CATHODE<br>12. COMMON ANODE<br>13. ANODE/CATHODE<br>14. ANODE/CATHODE | STYLE 8:<br>PIN 1. COMMON CATHODE<br>2. ANODE/CATHODE<br>3. ANODE/CATHODE<br>4. NO CONNECTION<br>5. ANODE/CATHODE<br>6. ANODE/CATHODE<br>7. COMMON ANODE<br>9. ANODE/CATHODE<br>10. ANODE/CATHODE<br>11. NO CONNECTION<br>12. ANODE/CATHODE<br>13. ANODE/CATHODE<br>14. COMMON CATHODE |

| DOCUMENT NUMBER:   | 98ASB42565B | Electronic versions are uncontrolled except when accessed directly from the Document Repository.<br>Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |             |  |
|--|-------------|---|-------------|--|
| DESCRIPTION:   | SOIC-14 NB  |   | PAGE 2 OF 2 |  |
| ON Semiconductor and M are trademarks of Semiconductor Components Industries 11 C dba ON Semiconductor or its subsidiaries in the United States and/or other countries |             |   |             |  |

ON Semiconductor and united states and/or other countries. LC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.





| DOCUMENT NUMBER:  | 98ASB14087C | Electronic versions are uncontrolled except when accessed directly from the Document Repository.<br>Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |             |  |
|---|-------------|---|-------------|--|
| DESCRIPTION:  | MICRO8      |   | PAGE 1 OF 1 |  |
| ON Semiconductor and ware trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries.<br>ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding<br>the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically<br>disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the<br>rights of others. |             |   |             |  |





may or may not be present.

| DOCUMENT NUMBER:   | 98ASH70246A | Electronic versions are uncontrolled except when accessed directly from the Document Repository.<br>Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |             |  |
|--|-------------|---|-------------|--|
| DESCRIPTION:   | TSSOP-14 WB |   | PAGE 1 OF 1 |  |
| ON Semiconductor and unarrest and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries.<br>ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others. |             |   |             |  |

DIMENSIONS: MILLIMETERS

© Semiconductor Components Industries, LLC, 2019

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor date sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use a a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor houteds for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

#### TECHNICAL SUPPORT

ON Semiconductor Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800–282–9855 Toll Free USA/Canada Phone: 011 421 33 790 2910 Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative

# **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

# ON Semiconductor:

NCV33202VDR2 NCV33202VDR2G NCV33204DR2 NCV33204DR2G NCV33204DTBR2 NCV33204DTBR2G MC33201D MC33201DG MC33201DR2 MC33201DR2G MC33201P MC33201PG MC33201VD MC33201VDG MC33201VDR2 MC33201VDR2G MC33202D MC33202DG MC33202DMR2 MC33202DMR2G MC33202DR2 MC33202DR2G MC33202P MC33202PG MC33202VD MC33202VDG MC33202VDR2 MC33202VDR2G MC33202VP MC33202VPG MC33204D MC33204DG MC33204DR2 MC33204DR2G MC33204DTB MC33204DTBG MC33204DTBR2 MC33204DTBR2G MC33204PG MC33204PG MC33204VD MC33204VDG MC33204VDR2 MC33204VDR2G MC33204VP MC33204VPG NCV33202DMR2G SCY33202DR2G SCY33201DR2G TCA80122W